

### GENERAL DESCRIPTION

The SGM2049C is a high accuracy, low noise, very low dropout linear regulator. It is capable of supplying 2A output current with typical dropout voltage of only 80mV. The operating input voltage range is from 1.1V to 7V with BIAS and 1.4V to 7V without BIAS. The output voltage of the SGM2049C can be set from 0.8V to 3.95V in pin-selectable operation and adjusted from 0.8V to 5.2V by using an external resistor divider.

Other features include logic-controlled shutdown mode, short-circuit current limit and thermal shutdown protection. The SGM2049C has automatic discharge function to quickly discharge  $V_{OUT}$  in the disabled status.

The SGM2049C is suitable for application which needs high accuracy, low noise and high current power supply, such as analog-to-digital converters (ADCs), digital-to-analog converters (DACs) and RF components.

With very high accuracy, remote sensing, and soft-start capabilities to reduce inrush current, the SGM2049C ensures the optimal system performance for powering digital loads such as FPGAs, DSPs and ASICs.

The SGM2049C is available in Green TQFN-3.5×3.5-20L and TQFN-5×5-20L packages. It operates over an operating temperature range of -40°C to +125°C.

### APPLICATIONS

Wireless Equipment  
 Industrial, Instrumentation and Medical  
 ADC and DAC  
 ATE

### FEATURES

- **Operating Input Voltage Range:**
  - ◆ **With BIAS: 1.1V to 7V**
  - ◆ **Without BIAS: 1.4V to 7V**
- **Output Voltage Range:**
  - ◆ **Adjustable Operation: 0.8V to 5.2V**
  - ◆ **Pin-Selectable Operation: 0.8V to 3.95V**
- **Output Voltage Accuracy: ±1% at +25°C**
- **Low Dropout Voltage: 80mV (TYP) at 2A**
- **Low Noise: 5µV<sub>RMS</sub> (TYP) with BIAS**
- **Excellent Load and Line Transient Responses**
- **With Output Automatic Discharge**
- **Adjustable Soft-Start Inrush Control**
- **Support Power-Good Indicator Function**
- **-40°C to +125°C Operating Temperature Range**
- **Available in Green TQFN-3.5×3.5-20L and TQFN-5×5-20L Packages**

### TYPICAL APPLICATION

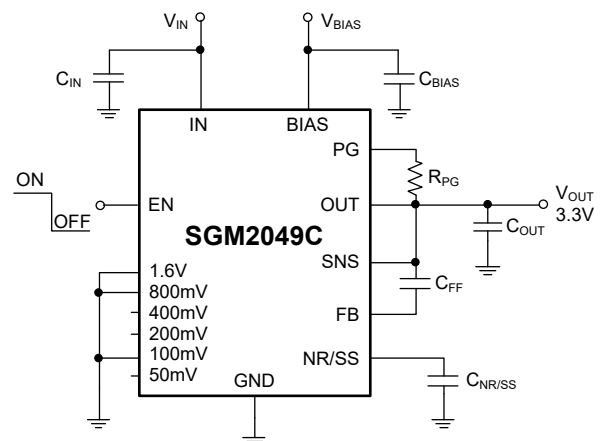


Figure 1. Typical Application Circuit

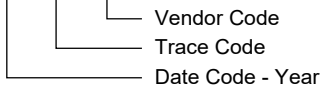
**PACKAGE/ORDERING INFORMATION**

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM2049C	TQFN-3.5×3.5-20L	-40°C to +125°C	SGM2049CXTRL20G/TR	SGM2049 XTRL20 XXXXX	Tape and Reel, 4000
	TQFN-5×5-20L	-40°C to +125°C	SGM2049CXTRM20G/TR	SGM2049 XTRM20 XXXXX	Tape and Reel, 3000

**MARKING INFORMATION**

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

**XXXXX**



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

**ABSOLUTE MAXIMUM RATINGS**

IN, BIAS, PG, EN to GND	-0.3V to 8V
SNS, OUT to GND	-0.3V to Min(V <sub>IN</sub> + 0.3V, 8V)
NR/SS, FB to GND	-0.3V to 3.6V
50mV, 100mV, 200mV, 400mV, 800mV, 1.6V to GND	
	-0.3V to (V <sub>OUT</sub> + 0.3V)
PG Current (Sink Current into Device)	5mA
Package Thermal Resistance	
TQFN-3.5×3.5-20L, θ <sub>JA</sub>	40°C/W
TQFN-3.5×3.5-20L, θ <sub>JB</sub>	14°C/W
TQFN-3.5×3.5-20L, θ <sub>JC</sub>	29°C/W
TQFN-5×5-20L, θ <sub>JA</sub>	37°C/W
TQFN-5×5-20L, θ <sub>JB</sub>	13°C/W
TQFN-5×5-20L, θ <sub>JC</sub>	19°C/W
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	6000V
CDM	1000V

**RECOMMENDED OPERATING CONDITIONS**

Input Supply Voltage Range	1.1V to 7V
Bias Supply Voltage Range <sup>(1)</sup>	3V to 7V
Output Voltage Range	0.8V to 5.2V
Enable Voltage Range	0V to V <sub>IN</sub>
Output Current	0A to 2A
Input Effective Capacitance, C <sub>IN</sub>	5µF (MIN)
Output Effective Capacitance, C <sub>OUT</sub>	10µF to 1000µF
Bias Effective Capacitance, C <sub>BIAS</sub>	5µF (MIN)
Power-Good Pull-Up Resistance	10kΩ to 100kΩ
Operating Junction Temperature Range	-40°C to +125°C

NOTE:

1. Bias supply voltage is required when V<sub>IN</sub> < 1.4V and not required when V<sub>IN</sub> ≥ 1.4V.

**OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

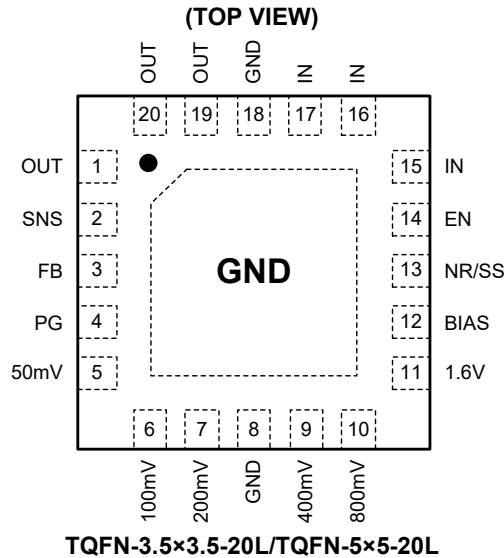
**ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

**DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS



PIN DESCRIPTION

PIN	NAME	FUNCTION
1, 19, 20	OUT	Regulator Output Pin. It is recommended to use an output capacitor with effective capacitance in the range of 10μF to 1000μF to ensure stability. This ceramic capacitor should be placed as close as possible to OUT pin.
2	SNS	Output Voltage Sense Input Pin. The SNS pin is connected to the load side of the output trace only when the pin-selectable programming mode is used. Keep SNS pin floating if the V <sub>OUT</sub> voltage is set by external resistor.
3	FB	Feedback Voltage Input Pin. Connect this pin to the midpoint of an external resistor divider to adjust the output voltage. Place the resistors as close as possible to this pin.
4	PG	Power-Good Indicator Output Pin. An open-drain, active-high output that indicates the status of V <sub>OUT</sub> . When the output voltage reaches V <sub>IT(PG)</sub> of the target, the PG pin goes into a high-impedance state.
5	50mV	Output Voltage Setting Pins. Select the desired output voltage by connecting these pins to the ground. Connecting these pins to the ground increases the output voltage value corresponding to the pin name. Multiple pins can be connected to GND at the same time. When V <sub>OUT</sub> is set by an external resistor, leave these pins floating (open).
6	100mV	
7	200mV	
9	400mV	
10	800mV	
11	1.6V	
12	BIAS	Bias Supply Voltage Pin for Internal Control Circuits. This pin is monitored by internal under-voltage lockout circuit and enables the use of low-input voltage, low-output voltage conditions (V <sub>IN</sub> < 1.4V).
13	NR/SS	Noise-Reduction and Soft-Start Pin. Using an external capacitor C <sub>NR/SS</sub> to decouple this pin to GND can not only reduce output noise to very low level but also slow down the V <sub>OUT</sub> rise like a soft-start behavior.
14	EN	Enable Pin. Drive EN high to turn on the regulator. Drive EN low to turn off the regulator. This pin must be connected to IN or BIAS pin if enable functionality is not used.
15, 16, 17	IN	Input Supply Voltage Pin. It is recommended to use a 10μF or larger ceramic capacitor from IN pin to ground to get good power supply decoupling. This ceramic capacitor should be placed as close as possible to IN pin.
8, 18	GND	Ground.
Exposed Pad	GND	Exposed Pad. Connect it to GND internally. Connect it to a large ground plane to maximize thermal performance. This pad is not an electrical connection point.

## ELECTRICAL CHARACTERISTICS

( $V_{IN} = (V_{OUT(NOM)} + 0.4V)$  or 1.4V (whichever is greater),  $V_{BIAS} = \text{Open}$ ,  $V_{OUT(NOM)} = 0.8V$ ,  $V_{EN} = 1.1V$ ,  $C_{IN} = 10\mu F$ ,  $C_{OUT} = 22\mu F$ ,  $C_{NR/SS} = 0nF$ ,  $C_{FF} = 0nF$  and PG pin pulled up to  $V_{IN}$  with 100k $\Omega$ ,  $T_J = -40^\circ C$  to  $+125^\circ C$ , typical values are at  $T_J = +25^\circ C$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Input Supply Voltage Range	$V_{IN}$		1.1		7	V	
Bias Supply Voltage Range	$V_{BIAS}$	$V_{IN} = 1.1V$	3		7	V	
Output Voltage Range	$V_{OUT}$	Pin-selectable operation	0.8		3.95	V	
		Adjustable operation, using external resistors	0.8		5.2		
Output Voltage Accuracy	$V_{OUT}$	$V_{IN} = 1.4V$ to 7V without BIAS, or $V_{IN} = 1.1V$ , $V_{BIAS} = 3V$ to 7V, $I_{OUT} = 5mA$ to 2A	$T_J = +25^\circ C$	-1		1	%
			$T_J = -40^\circ C$ to $+125^\circ C$	-1.7		1.3	
		Pin-selectable operation, $I_{OUT} = 5mA$	$T_J = +25^\circ C$	-1.4		1.4	
			$T_J = -40^\circ C$ to $+125^\circ C$	-2		2	
Feedback Voltage	$V_{FB}$	$T_J = +25^\circ C$	0.792	0.8	0.808	V	
			0.784		0.816		
FB Pin Leakage Current	$I_{FB}$	$V_{IN} = 7V$	-120		120	nA	
Input Supply UVLO with Bias	$V_{UVLO1(IN)}$	$V_{IN}$ rising with $V_{BIAS} = 3V$		0.78	0.95	V	
$V_{UVLO1(IN)}$ Hysteresis	$V_{HYS1(IN)}$	$V_{BIAS} = 3V$		100		mV	
Input Supply UVLO without Bias	$V_{UVLO2(IN)}$	$V_{IN}$ rising		1.14	1.4	V	
$V_{UVLO2(IN)}$ Hysteresis	$V_{HYS2(IN)}$			40		mV	
Bias Supply UVLO	$V_{UVLO(BIAS)}$	$V_{BIAS}$ rising, $V_{IN} = 1.1V$		2.5	2.8	V	
$V_{UVLO(BIAS)}$ Hysteresis	$V_{HYS(BIAS)}$	$V_{IN} = 1.1V$		260		mV	
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$V_{IN} = 1.4V$ to 7V, $I_{OUT} = 5mA$		0.04	1.5	mV/V	
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	$V_{BIAS} = 3V$ to 7V, $V_{IN} = 1.1V$ , $I_{OUT} = 5mA$ to 2A		0.1	1.8	mV/A	
		$I_{OUT} = 5mA$ to 2A		0.1	2.2		
		$I_{OUT} = 5mA$ to 2A, $V_{OUT} = 5.2V$		0.7	4.5		
Dropout Voltage	$V_{DROP}$	$V_{IN} = 1.4V$ , $I_{OUT} = 2A$ , $V_{FB} = 0.776V$		80	125	mV	
		$V_{IN} = 5.2V$ , $I_{OUT} = 2A$ , $V_{FB} = 0.776V$		80	125		
		$V_{IN} = 1.1V$ , $V_{BIAS} = 5V$ , $I_{OUT} = 2A$ , $V_{FB} = 0.776V$		80	125		
Output Current Limit	$I_{LIMIT}$	$V_{OUT}$ forced at $90\% \times V_{OUT(NOM)}$ , $V_{IN} = V_{OUT(NOM)} + 0.4V$	2.2	3.2	4	A	
Short-Circuit Current Limit	$I_{SHORT}$	$R_{LOAD} = 20m\Omega$ , under foldback operation		1.7		A	
GND Pin Current	$I_{GND}$	$V_{IN} = 7V$ , $I_{OUT} = 5mA$		3.3	4.1	mA	
		$V_{IN} = 1.4V$ , $I_{OUT} = 2A$		2.3	3		
Shutdown Current	$I_{SHDN}$	PG = Open, $V_{IN} = 7V$ , $V_{EN} = 0.5V$ , $T_J = +25^\circ C$		1.4	3	$\mu A$	
		PG = Open, $V_{IN} = 7V$ , $V_{EN} = 0.5V$			15		
EN Pin High-Level Input Voltage	$V_{IH(EN)}$	EN input voltage "H"	1.1		7	V	
EN Pin Low-Level Input Voltage	$V_{IL(EN)}$	EN input voltage "L"	0		0.5	V	
EN Pin Current	$I_{EN}$	$V_{IN} = 7V$ , $V_{EN} = 0V$ and 7V	-0.3		0.3	$\mu A$	
Output Discharge Resistance	$R_{DIS}$	$V_{IN} = 1.4V$ , $V_{EN} = 0V$ , $V_{OUT} = 0.5V$	190	260	330	$\Omega$	
Turn-On Time	$t_{ON}$	From assertion of $V_{EN}$ to $V_{OUT} = 90\% \times V_{OUT(NOM)}$		300		$\mu s$	

**ELECTRICAL CHARACTERISTICS (continued)**

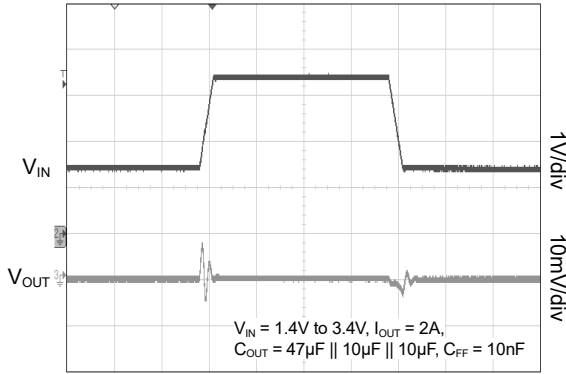
( $V_{IN} = (V_{OUT(NOM)} + 0.4V)$  or 1.4V (whichever is greater),  $V_{BIAS} = \text{Open}$ ,  $V_{OUT(NOM)} = 0.8V$ ,  $V_{EN} = 1.1V$ ,  $C_{IN} = 10\mu F$ ,  $C_{OUT} = 22\mu F$ ,  $C_{NR/SS} = 0nF$ ,  $C_{FF} = 0nF$  and PG pin pulled up to  $V_{IN}$  with 100kΩ,  $T_J = -40^\circ C$  to  $+125^\circ C$ , typical values are at  $T_J = +25^\circ C$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
PG Pin Threshold	$V_{IT(PG)}$	For falling $V_{OUT}$	$84\% \times V_{OUT}$	$89\% \times V_{OUT}$	$93\% \times V_{OUT}$	V
PG Pin Hysteresis	$V_{HYS(PG)}$	For rising $V_{OUT}$		$1.7\% \times V_{OUT}$		V
PG Pin Low-Level Output Voltage	$V_{OL(PG)}$	$V_{OUT} < V_{IT(PG)}$ , $I_{PG} = -1mA$ (current into device)		0.17	0.3	V
PG Pin Leakage Current	$I_{IK9(PG)}$	$V_{OUT} > V_{IT(PG)}$ , $V_{PG} = 7V$ , $V_{IN} = 7V$		0.01	0.5	μA
NR/SS Pin Charging Current	$I_{NR/SS}$	$V_{NR/SS} = GND$ , $V_{IN} = 7V$	3.5	5.8	8.5	μA
NR/SS Pin Voltage	$V_{NR/SS}$			0.8		V
BIAS Pin Current	$I_{BIAS}$	$V_{IN} = 1.1V$ , $V_{BIAS} = 7V$ , $V_{OUT(NOM)} = 0.8V$ , $I_{OUT} = 2A$		2.9	3.6	mA
Power Supply Rejection Ratio	PSRR	$V_{IN}$ to $V_{OUT}$ , $V_{OUT} = 0.8V$ , ( $V_{IN} - V_{OUT}$ ) = 0.4V, $V_{BIAS} = 5V$ , $I_{OUT} = 2A$ , $C_{NR/SS} = 100nF$ , $C_{FF} = 10nF$ , $C_{OUT} = 22\mu F$	$f = 10kHz$	51		dB
			$f = 500kHz$	23		
			$f = 10kHz$	47		
			$f = 500kHz$	20		
Output Voltage Noise	$e_n$	$f = 10Hz$ to $100kHz$ , $I_{OUT} = 2A$ , $C_{NR/SS} = 100nF$ , $C_{FF} = 10nF$	$V_{OUT} = 0.8V$ , $V_{IN} = 1.1V$ , $V_{BIAS} = 5V$	5		μV <sub>RMS</sub>
			$V_{OUT} = 5V$ , $V_{IN} = 5.4V$ , $V_{BIAS} = 0V$	11		
Thermal Shutdown Temperature	$T_{SHDN}$			165		°C
Thermal Shutdown Hysteresis	$\Delta T_{SHDN}$			25		°C

TYPICAL PERFORMANCE CHARACTERISTICS

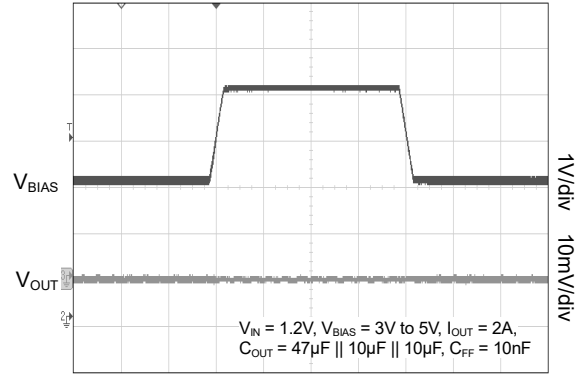
$T_J = +25^{\circ}\text{C}$ ,  $V_{IN} = (V_{OUT(NOM)} + 0.4\text{V})$  or  $1.4\text{V}$  (whichever is greater),  $V_{BIAS} = \text{Open}$ ,  $V_{OUT(NOM)} = 0.8\text{V}$ ,  $V_{EN} = 1.1\text{V}$ ,  $C_{IN} = 10\mu\text{F}$ ,  $C_{OUT} = 22\mu\text{F}$ ,  $C_{NR/SS} = 0\text{nF}$ , no  $C_{FF}$ , and PG pin pulled up to  $V_{IN}$  with  $100\text{k}\Omega$ , unless otherwise noted.

$V_{IN}$  Line Transient Response without BIAS



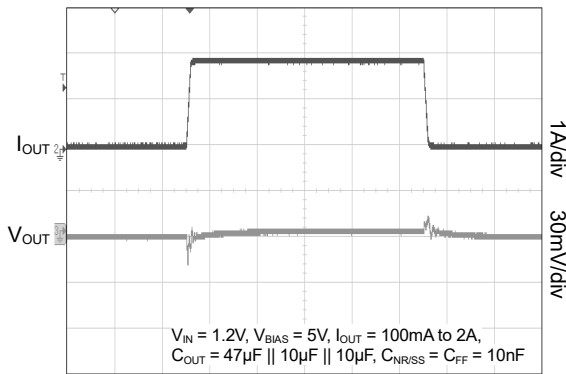
Time (50µs/div)

$V_{BIAS}$  Line Transient Response



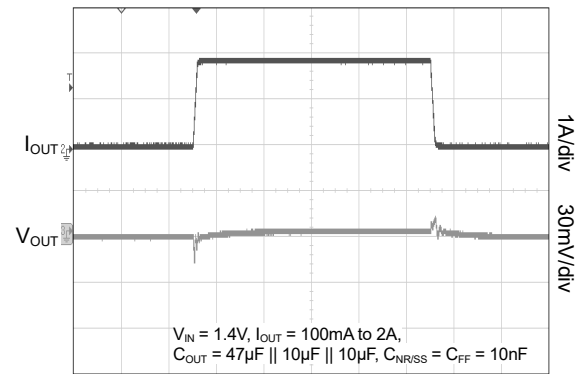
Time (50µs/div)

Load Transient Response with BIAS



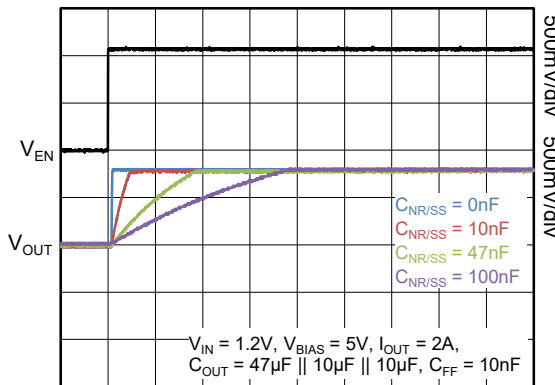
Time (200µs/div)

Load Transient Response without BIAS



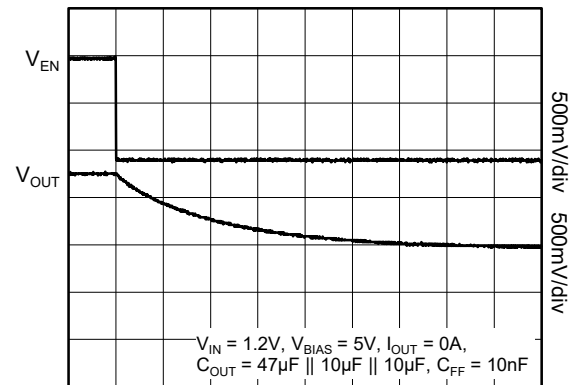
Time (200µs/div)

Enable Turn-On Response



Time (5ms/div)

Enable Turn-Off Response

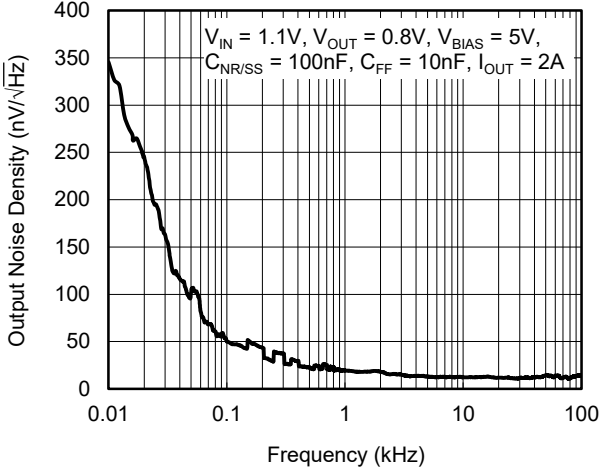


Time (5ms/div)

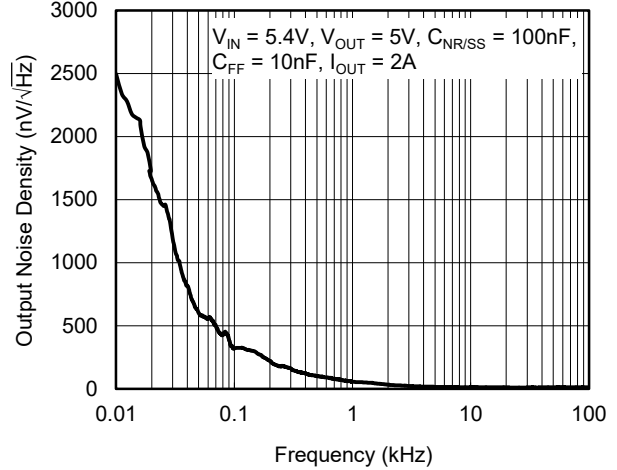
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$T_J = +25^\circ\text{C}$ ,  $V_{IN} = (V_{OUT(NOM)} + 0.4\text{V})$  or 1.4V (whichever is greater),  $V_{BIAS} = \text{Open}$ ,  $V_{OUT(NOM)} = 0.8\text{V}$ ,  $V_{EN} = 1.1\text{V}$ ,  $C_{IN} = 10\mu\text{F}$ ,  $C_{OUT} = 22\mu\text{F}$ ,  $C_{NR/SS} = 0\text{nF}$ , no  $C_{FF}$ , and PG pin pulled up to  $V_{IN}$  with 100k $\Omega$ , unless otherwise noted.

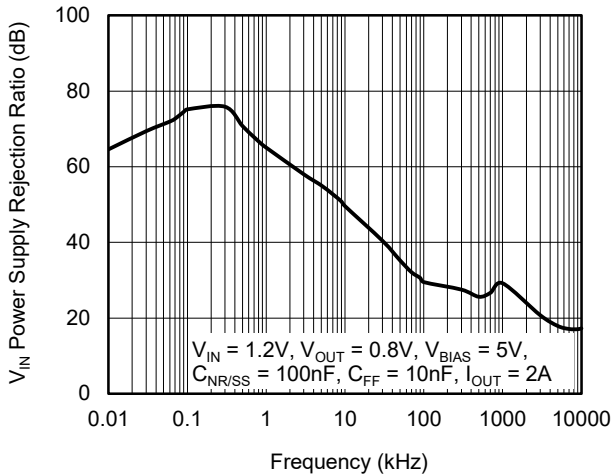
Output Noise Density vs. Frequency



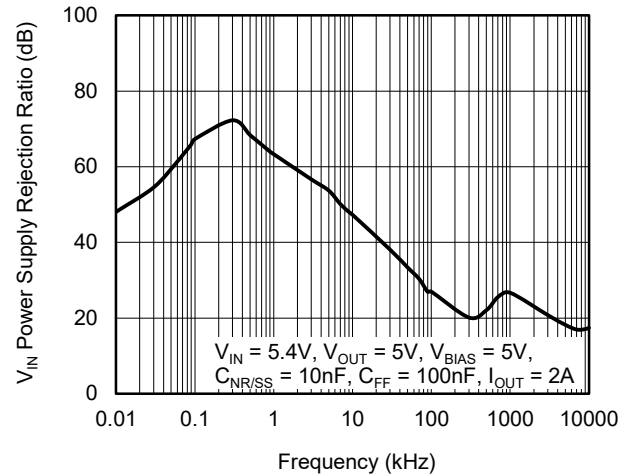
Output Noise Density vs. Frequency



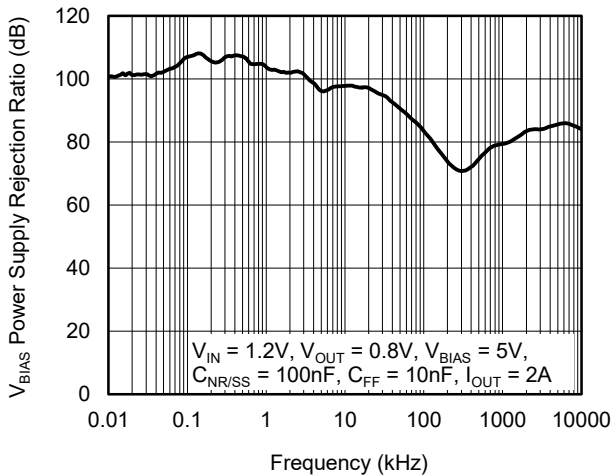
$V_{IN}$  Power Supply Rejection Ratio vs. Frequency



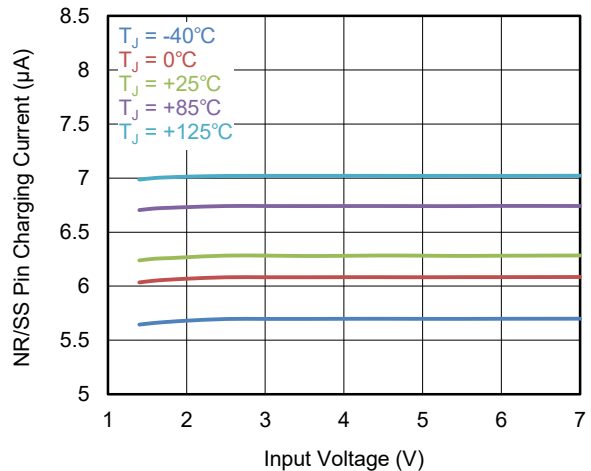
$V_{IN}$  Power Supply Rejection Ratio vs. Frequency



$V_{BIAS}$  Power Supply Rejection Ratio vs. Frequency



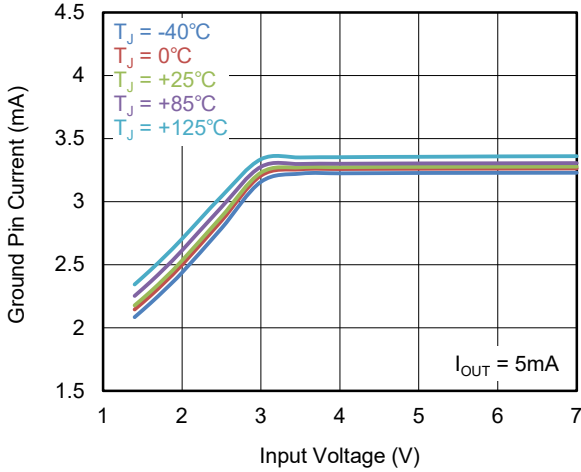
NR/SS Pin Charging Current vs. Input Voltage



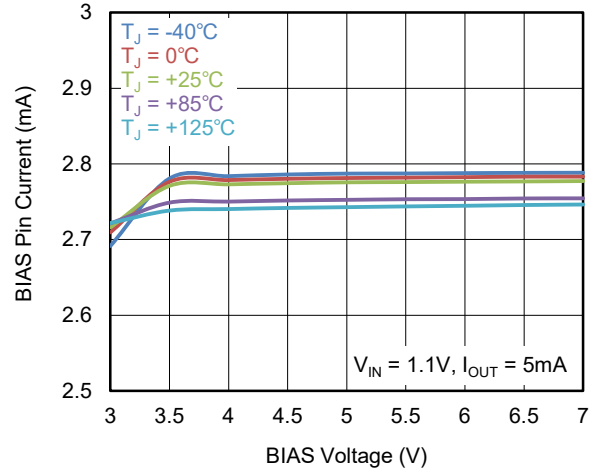
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$T_J = +25^\circ\text{C}$ ,  $V_{IN} = (V_{OUT(NOM)} + 0.4\text{V})$  or  $1.4\text{V}$  (whichever is greater),  $V_{BIAS} = \text{Open}$ ,  $V_{OUT(NOM)} = 0.8\text{V}$ ,  $V_{EN} = 1.1\text{V}$ ,  $C_{IN} = 10\mu\text{F}$ ,  $C_{OUT} = 22\mu\text{F}$ ,  $C_{NR/SS} = 0\text{nF}$ , no  $C_{FF}$ , and PG pin pulled up to  $V_{IN}$  with  $100\text{k}\Omega$ , unless otherwise noted.

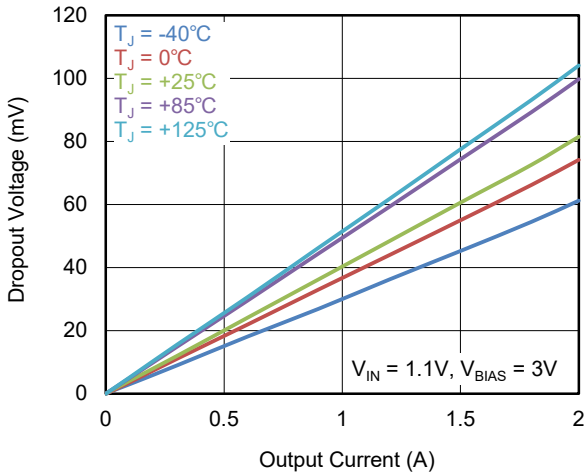
Ground Pin Current vs. Input Voltage



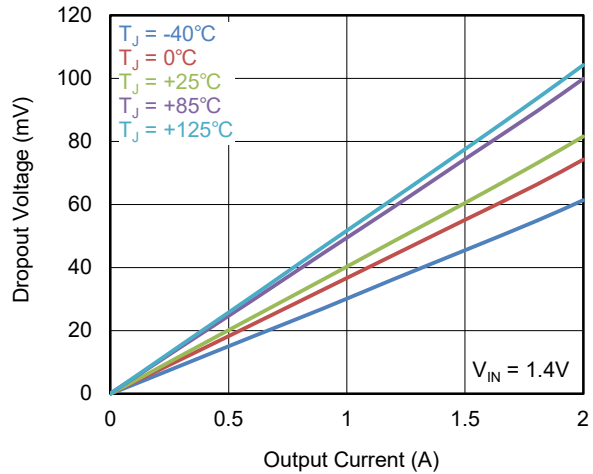
BIAS Pin Current vs. BIAS Voltage



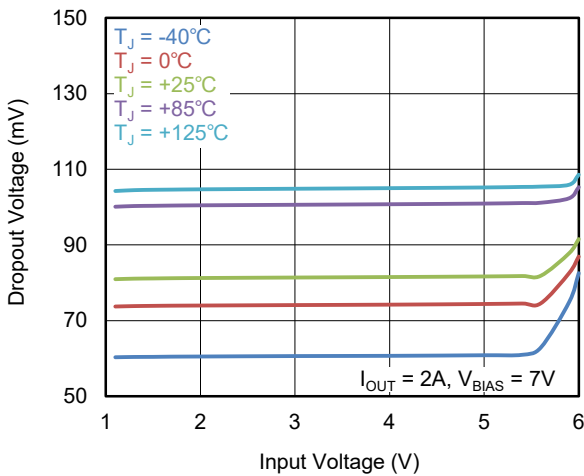
Dropout Voltage vs. Output Current with BIAS



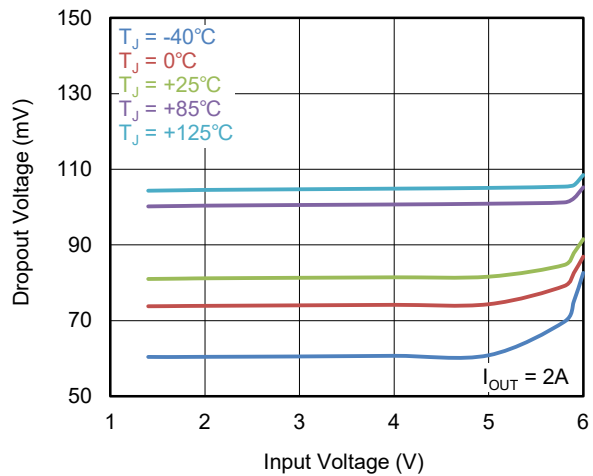
Dropout Voltage vs. Output Current without BIAS



Dropout Voltage vs. Input Voltage with BIAS



Dropout Voltage vs. Input Voltage without BIAS

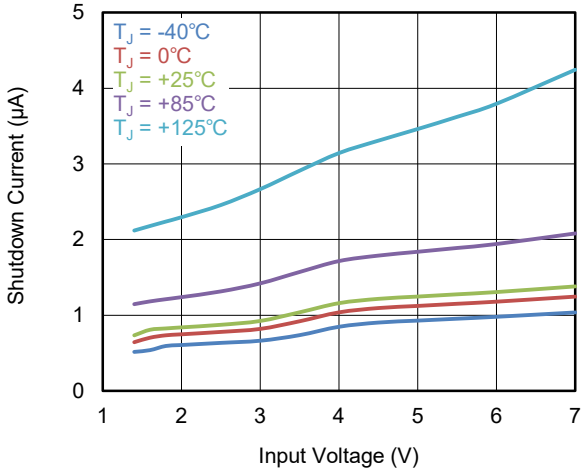




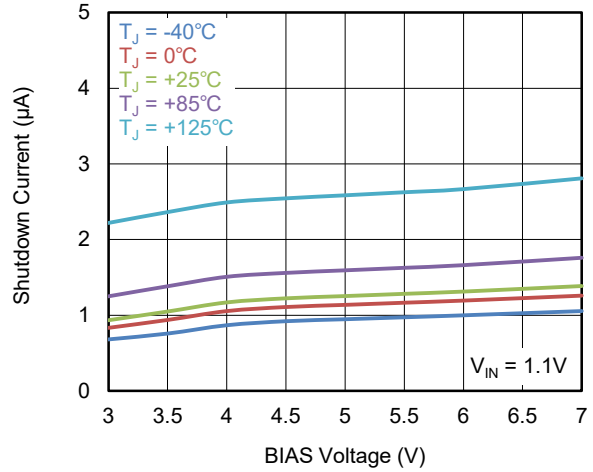
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$T_J = +25^\circ\text{C}$ ,  $V_{IN} = (V_{OUT(NOM)} + 0.4\text{V})$  or 1.4V (whichever is greater),  $V_{BIAS} = \text{Open}$ ,  $V_{OUT(NOM)} = 0.8\text{V}$ ,  $V_{EN} = 1.1\text{V}$ ,  $C_{IN} = 10\mu\text{F}$ ,  $C_{OUT} = 22\mu\text{F}$ ,  $C_{NR/SS} = 0\text{nF}$ , no  $C_{FF}$ , and PG pin pulled up to  $V_{IN}$  with 100k $\Omega$ , unless otherwise noted.

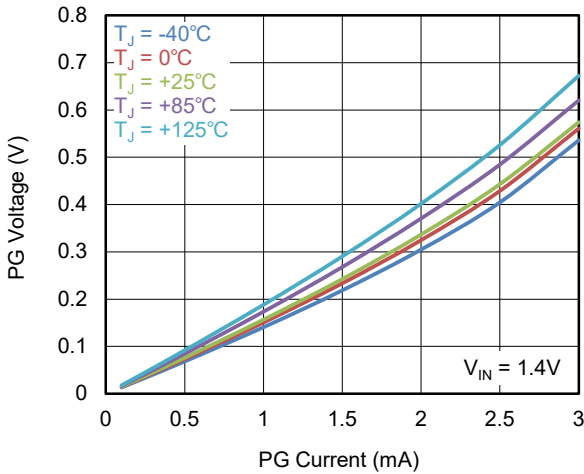
Shutdown Current vs. Input Voltage



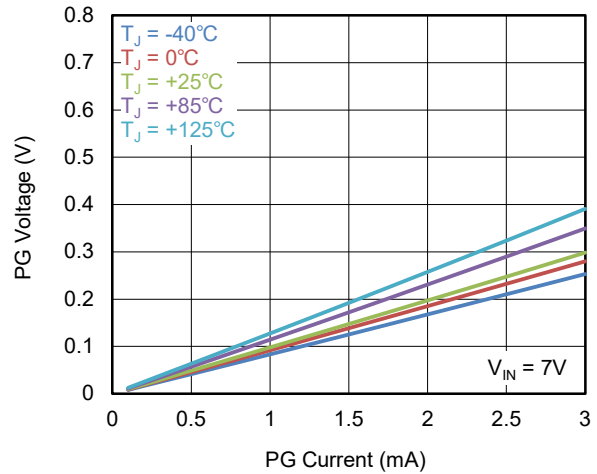
Shutdown Current vs. BIAS Voltage



PG Voltage vs. PG Current



PG Voltage vs. PG Current





APPLICATION INFORMATION

The SGM2049C is a high accuracy, low noise, fast transient response high performance LDO, it provides 2A output current. These features make the device a reliable solution to solve many challenging problems in the generation of clean and accurate power supply. The high performance also makes the SGM2049C useful in a variety of applications. The SGM2049C provides the protection functions for output overload, output short-circuit condition and overheating.

The SGM2049C provides an EN pin as an external chip enable control to enable/disable the device. When the regulator is in shutdown state, the shutdown current consumes as low as 1.4µA (TYP).

Input Capacitor Selection (C<sub>IN</sub>, C<sub>BIAS</sub>)

The input decoupling capacitor should be placed as close as possible to the IN pin and BIAS pin to ensure the device stability. C<sub>IN</sub> = 10µF/C<sub>BIAS</sub> = 5µF or larger X7R or X5R ceramic capacitors are selected to get good dynamic performance.

When V<sub>IN</sub> is required to provide large current instantaneously, a large effective input capacitor is required. Multiple input capacitors can limit the input tracking inductance. Adding more input capacitors is available to restrict the ringing and to keep it below the device absolute maximum ratings.

Output Capacitor Selection (C<sub>OUT</sub>)

The output capacitor should be placed as close as possible to the OUT pin. 10µF or larger X7R or X5R ceramic capacitor is selected to get good dynamic performance. The minimum effective capacitance of C<sub>OUT</sub> that SGM2049C can remain stable is 10µF. For ceramic capacitor, temperature, DC bias and package size will change the effective capacitance, so enough margin of C<sub>OUT</sub> must be considered in design. Additionally, C<sub>OUT</sub> with larger capacitance and lower ESR will help increase the high frequency PSRR and improve the load transient response.

Noise-Reduction and Soft-Start Capacitor Selection (C<sub>NR/SS</sub>)

The SGM2049C is designed for a programmable, monotonic soft-start time of output rising, and it can be

achieved via an external capacitor (C<sub>NR/SS</sub>) on the NR/SS pin. Using an external C<sub>NR/SS</sub> is recommended for general application. It not only minimizes the inrush current but also helps reduce the noise component from internal reference.

Adjustable Output Voltage

The SGM2049C can be set either with the internal pin-selectable network or by connecting with external resistors to achieve different output voltages. When the output voltage range is from 0.8V to 3.95V, the SGM2049C can be programmed by using the pin-selectable network. When the output voltage range is greater than 3.95V and up to 5.2V, external resistors must be used as shown in Figure 3. The output voltage is determined by the following equation:

$$V_{OUT} = 0.8V \times \left( 1 + \frac{R_1}{R_2} \right) \tag{1}$$

One parallel capacitor (C<sub>FF</sub> = 10nF) with R<sub>1</sub> can be used to improve the feedback loop stability and PSRR, increase the transient response and reduce the output noise. Use an R<sub>1</sub> approximately 12kΩ to maintain a 5µA minimum load.

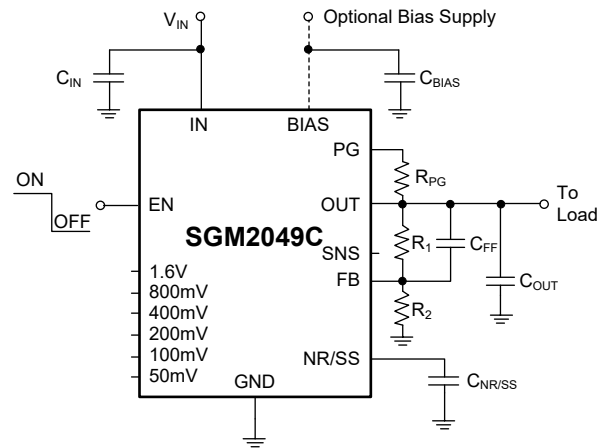


Figure 3. Adjustable Output Voltage Application

## APPLICATION INFORMATION (continued)

**Pin-Selectable Programmable Output Voltage**

Pin-selectable programmable output voltage is achieved with the pin-selectable resistors via pin 2 and pins 5 to 11. Each pin can be grounded (active) or floating (open) or connected to the SNS pin. Pin-selectable programming is set as the internal reference voltage by Equation 2 plus the accumulated sum of the respective voltages assigned to each active pin. Table 1 shows these voltage values related to each active pin setting for reference.

$$V_{OUT} = 0.8V + (\Sigma \text{ Pin-Selectable Pins to Ground}) \quad (2)$$

Table 1. Pin-Selectable Programmable Output Voltage

Pin-Selectable Program Pins (Active Low)	Additive Output Voltage Level
Pin 5 (50mV)	50mV
Pin 6 (100mV)	100mV
Pin 7 (200mV)	200mV
Pin 9 (400mV)	400mV
Pin 10 (800mV)	800mV
Pin 11 (1.6V)	1.6V

The output voltage is set according to Equation 1 as for the adjustable operation, but  $R_1$  and  $R_2$  are internally integrated and matched for higher accuracy. By reducing the value of  $R_1$  and connecting any of the pin-selectable pins to the SNS pin, the resolution of the internal feedback network can be improved.

**Enable Control**

The EN pin of the SGM2049C is used to enable/disable the device and to deactivate/activate the output automatic discharge function.

When the EN pin voltage is lower than  $V_{IL(EN)}$ , the device is in shutdown state. There is no current flowing from IN to OUT pins. In this state, the automatic discharge transistor is active to discharge the output voltage through a 260 $\Omega$  (TYP) resistor.

When the EN pin voltage is higher than  $V_{IH(EN)}$ , the device is in active state. The output voltage is regulated to the expected value and the automatic discharge transistor is turned off.

**Reverse Current Protection**

The pass transistor has an inherent body diode which will be forward biased in the case when  $V_{OUT} > (V_{IN} + 0.3V)$ . If extended reverse voltage operation is anticipated, external limiting might be appropriate.

**Negatively Biased Output**

When the output voltage is negative, the chip may not start up due to parasitic effects. Ensure that the output is greater than -0.3V under all conditions. If negatively biased output is excessive and expected in the application, a Schottky diode can be added between the OUT pin and GND pin.

**Output Current Limit and Short-Circuit Protection**

When overload events happen, the output current is internally limited to 3.2A (TYP). When the OUT pin is shorted to ground, the short-circuit protection will limit the output current to 1.7A (TYP).

**Thermal Shutdown**

The SGM2049C can detect the temperature of die. When the die temperature exceeds the threshold value of thermal shutdown, the SGM2049C will be in shutdown state and it will remain in this state until the die temperature decreases to +140°C.

**Power Dissipation ( $P_D$ )**

Power dissipation ( $P_D$ ) of the SGM2049C can be calculated by the equation  $P_D = (V_{IN} - V_{OUT}) \times I_{OUT}$ . Thermal shutdown protection starts when the power dissipation of the device is too high and the operating junction temperature exceeds +165°C.

The maximum allowable power dissipation ( $P_{D(MAX)}$ ) of the SGM2049C is affected by many factors, including the difference between junction temperature and ambient temperature ( $T_{J(MAX)} - T_A$ ), package thermal resistance from the junction to the ambient environment ( $\theta_{JA}$ ), the rate of ambient airflow and PCB layout.  $P_{D(MAX)}$  can be approximated by the following equation:

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA} \quad (3)$$

**REVISION HISTORY**

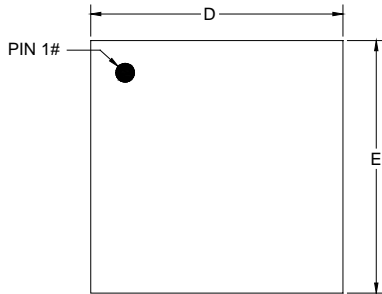
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>Changes from Original (MARCH 2023) to REV.A</b>	<b>Page</b>
Changed from product preview to production data.....	All

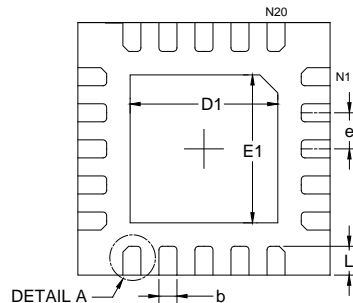
---

PACKAGE OUTLINE DIMENSIONS

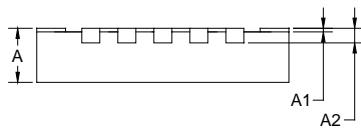
TQFN-3.5x3.5-20L



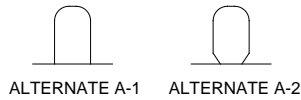
TOP VIEW



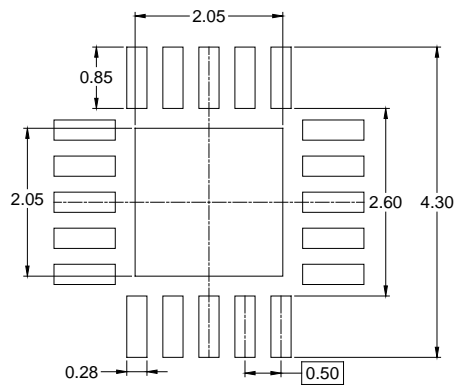
BOTTOM VIEW



SIDE VIEW



DETAIL A  
ALTERNATE TERMINAL  
CONSTRUCTION



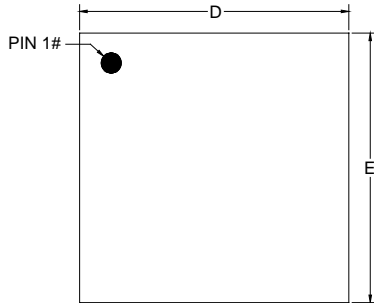
RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		
	MIN	MOD	MAX
A	0.700	0.750	0.800
A1	-	-	0.050
A2	0.203 REF		
D	3.450	3.500	3.550
D1	2.000	2.050	2.100
E	3.450	3.500	3.550
E1	2.000	2.050	2.100
b	0.200	0.250	0.300
e	0.500 BSC		
L	0.350	0.400	0.450

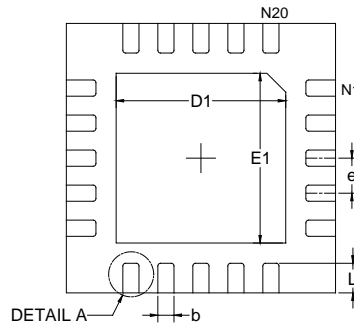
NOTE: This drawing is subject to change without notice.

PACKAGE OUTLINE DIMENSIONS

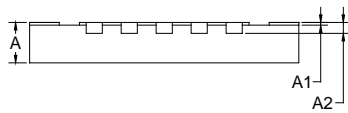
TQFN-5x5-20L



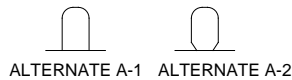
TOP VIEW



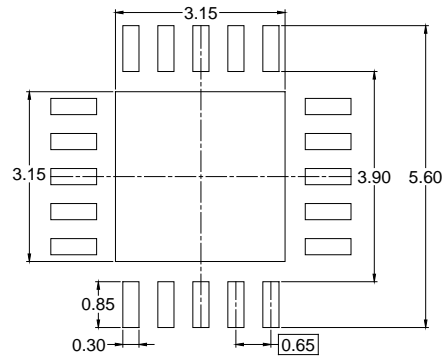
BOTTOM VIEW



SIDE VIEW



DETAIL A  
ALTERNATE TERMINAL  
CONSTRUCTION



RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		
	MIN	MOD	MAX
A	0.700	0.750	0.800
A1	0.000	-	0.050
A2	0.203 REF		
D	4.950	5.000	5.050
D1	3.100	3.150	3.200
E	4.950	5.000	5.050
E1	3.100	3.150	3.200
b	0.250	0.300	0.350
e	0.650 BSC		
L	0.500	0.550	0.600

NOTE: This drawing is subject to change without notice.

# PACKAGE INFORMATION

## TAPE AND REEL INFORMATION

### REEL DIMENSIONS



### TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TQFN-3.5×3.5-20L	13"	12.4	3.80	3.80	0.95	4.0	8.0	2.0	12.0	Q2
TQFN-5×5-20L	13"	12.4	5.30	5.30	1.10	4.0	8.0	2.0	12.0	Q2

DD00001



# PACKAGE INFORMATION

## CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

## KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5

DD0002

单击下面可查看定价，库存，交付和生命周期等信息

[>>SGMICRO\(圣邦微电子\)](#)